

## T498A335K010ZTE3K6

Obsolete

B45196P, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 3.3 uF, 10%, 10 VDC, SMD, Molded, High Temperature, N/A, 3.6 Ohms, 3216, Height Max = 1.8mm



General Information	
Series	B45196P
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

### Dimensions

Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
K	1.3mm TYP

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

### Specifications

Capacitance	3.3 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	3.6 Ohms (100kHz)
Ripple Current	144.3 mAmps (25C), 129.9 mAmps (85C), 57.7 mAmps (125C)
Leakage Current	0.5 uA